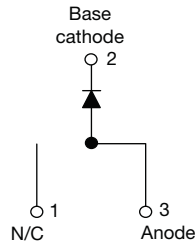


High Performance Schottky Rectifier, 16 A


D²PAK


FEATURES

- 150 °C T_J operation
- High frequency operation
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912


RoHS
 COMPLIANT
 HALOGEN
FREE

PRODUCT SUMMARY	
Package	TO-263AB (D ² PAK)
I _{F(AV)}	16 A
V _R	35 V, 45 V
V _F at I _F	0.63
I _{RM}	40 mA at 125 °C
T _J max.	150 °C
Diode variation	Single die
E _{AS}	24 mJ

DESCRIPTION

This VS-MBRB16... Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS			
SYMBOL	CHARACTERISTICS	VALUES	UNITS
I _{F(AV)}	Rectangular waveform	16	A
V _R		35/45	V
I _{FSM}	t _p = 5 μs sine	1800	A
V _F	16 A _{pk} , T _J = 125 °C	0.57	V
T _J		-65 to +150	°C

VOLTAGE RATINGS				
PARAMETER	SYMBOL	VS-MBRB1635PbF	VS-MBRB1645PbF	UNITS
Maximum DC reverse voltage	V _R	35	45	V
Maximum working peak reverse voltage	V _{RWM}			

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current	I _{F(AV)}	T _C = 134 °C, rated V _R		16	A
Non-repetitive peak surge current	I _{FSM}	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated V _{RRM} applied	1800	
		Surge applied at rated load condition half wave single phase 60 Hz		150	
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 3.6 A, L = 3.7 mH		24	mJ
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μs Frequency limited by T _J maximum V _A = 1.5 x V _R typical		3.6	A



ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop	$V_{FM}^{(1)}$	16 A	$T_J = 25\text{ }^\circ\text{C}$	0.63	V
			$T_J = 125\text{ }^\circ\text{C}$	0.57	
Maximum instantaneous reverse current	$I_{RM}^{(1)}$	$T_J = 25\text{ }^\circ\text{C}$	Rated DC voltage	0.2	mA
		$T_J = 125\text{ }^\circ\text{C}$		40	
Maximum junction capacitance	C_T	$V_R = 5\text{ }V_{DC}$ (test signal range 100 kHz to 1 MHz), $25\text{ }^\circ\text{C}$		1400	pF
Typical series inductance	L_S	Measured lead from top of terminal to mounting plane		8.0	nH
Maximum voltage rate of change	dV/dt	Rated V_R		10 000	V/ μs

Note(1) Pulse width < 300 μs , duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum junction temperature range	T_J			-65 to +150	$^\circ\text{C}$
Maximum storage temperature range	T_{Stg}			-65 to +175	
Maximum thermal resistance, junction to case	R_{thJC}	DC operation		1.50	$^\circ\text{C}/\text{W}$
Typical thermal resistance, case to heatsink	R_{thCS}	Mounting surface, smooth and greased		0.50	
Approximate weight				2	g
				0.07	oz.
Mounting torque	minimum			6 (5)	kgf · cm (lbf · in)
	maximum			12 (10)	
Marking device		Case style D ² PAK		MBRB1635	

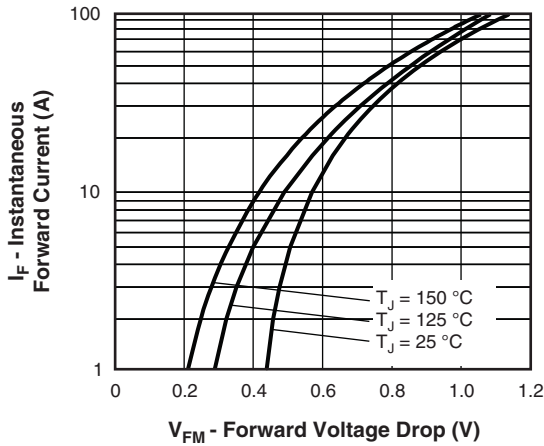


Fig. 1 - Maximum Forward Voltage Drop Characteristics

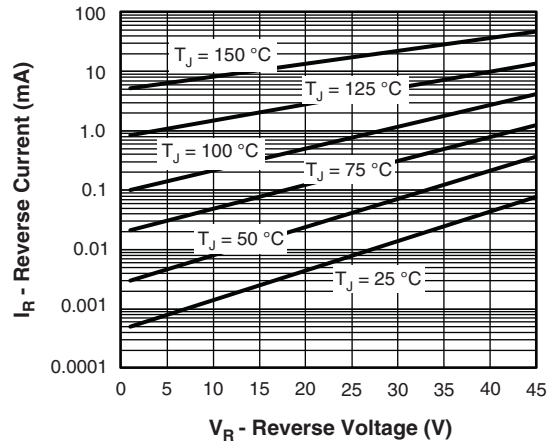


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

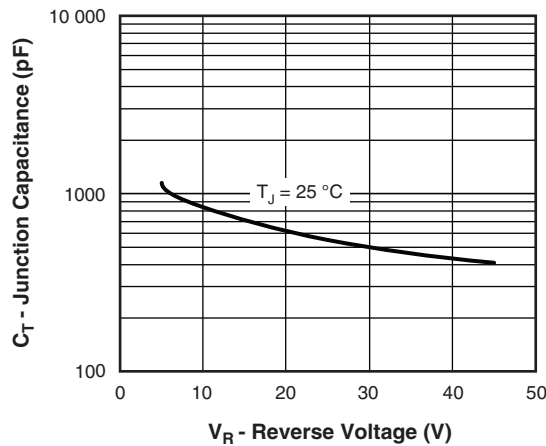


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

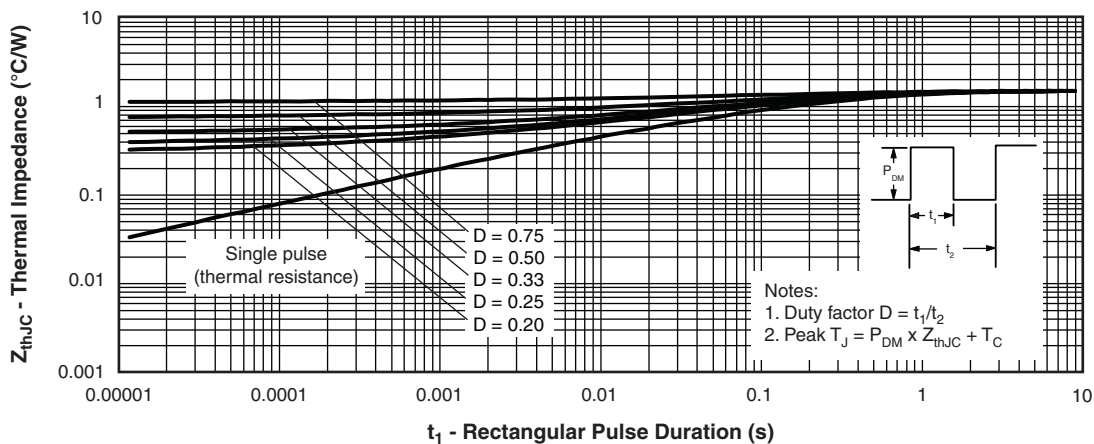


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

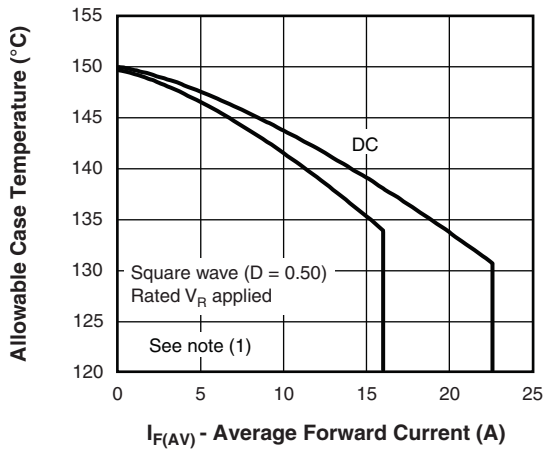


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

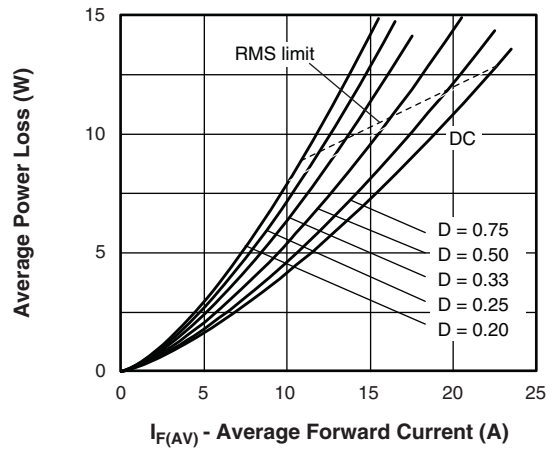


Fig. 6 - Forward Power Loss Characteristics

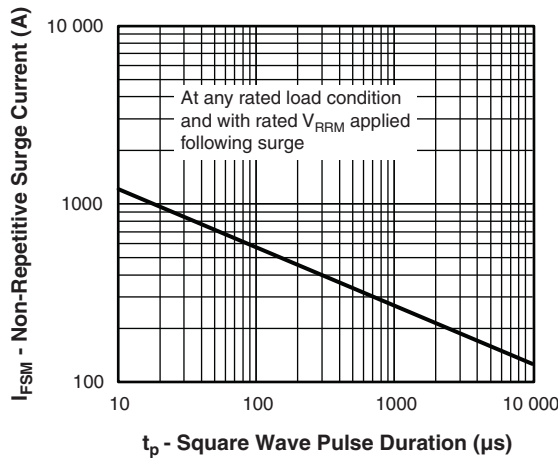


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

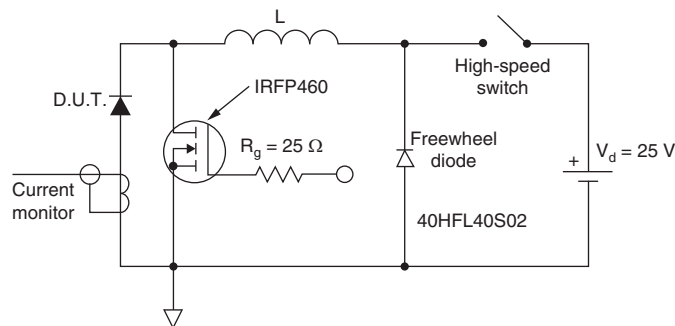


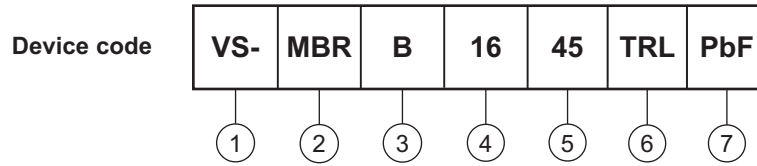
Fig. 8 - Unclamped Inductive Test Circuit

Note

- (1) Formula used: $T_C = T_J - (P_d + P_{dREV}) \times R_{thJC}$;
 P_d = forward power loss = $I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig. 6);
 P_{dREV} = inverse power loss = $V_{R1} \times I_R (1 - D)$; I_R at V_{R1} = rated V_R applied



ORDERING INFORMATION TABLE



- 1** - Vishay Semiconductors product
- 2** - Essential part number
- 3** - B = surface mount
- 4** - Current rating (16 = 16 A)
- 5** - Voltage code = V_{RRM}

35 = 35 V
45 = 45 V
- 6** -
 - None = tube (50 pieces)
 - TRL = tape and reel (left oriented)
 - TRR = tape and reel (right oriented)
- 7** - PbF = lead (Pb)-free

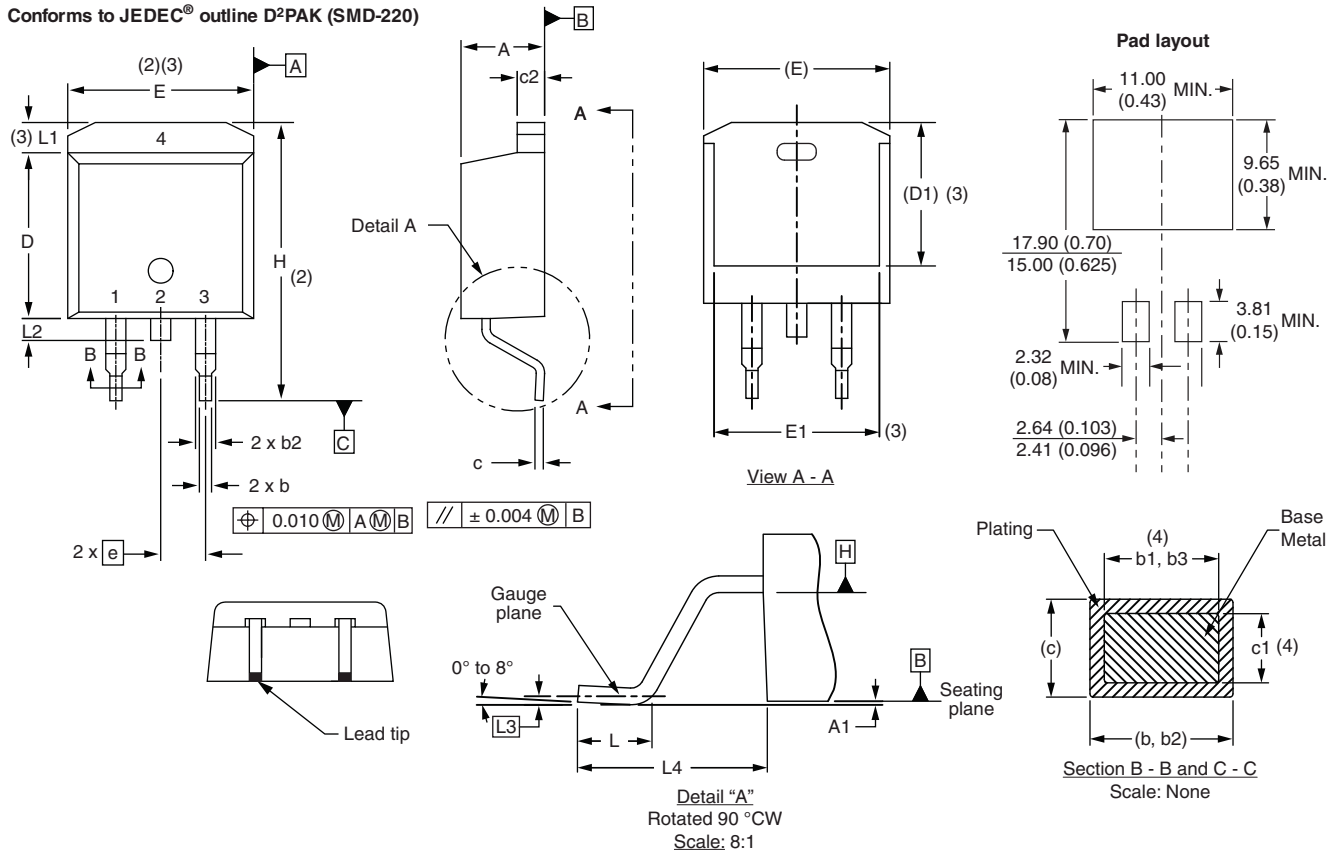
ORDERING INFORMATION			
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION
VS-MBRB1635PbF	50	1000	Antistatic plastic tubes
VS-MBRB1635TRRPbF	800	800	13" diameter reel
VS-MBRB1635TRLPbF	800	800	13" diameter reel
VS-MBRB1645PbF	50	1000	Antistatic plastic tubes
VS-MBRB1645TRRPbF	800	800	13" diameter reel
VS-MBRB1645TRLPbF	800	800	13" diameter reel

LINKS TO RELATED DOCUMENTS	
Dimensions	www.vishay.com/doc?95046
Part marking information	www.vishay.com/doc?95054
Packaging information	www.vishay.com/doc?95032
SPIICE model	www.vishay.com/doc?95407

D²PAK

DIMENSIONS in millimeters and inches

Conforms to JEDEC[®] outline D²PAK (SMD-220)



SYMBOL	MILLIMETERS		INCHES		NOTES	SYMBOL	MILLIMETERS		INCHES		NOTES
	MIN.	MAX.	MIN.	MAX.			MIN.	MAX.	MIN.	MAX.	
A	4.06	4.83	0.160	0.190		D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010		E	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039		E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4	e	2.54 BSC		0.100 BSC		
b2	1.14	1.78	0.045	0.070		H	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4	L	1.78	2.79	0.070	0.110	
c	0.38	0.74	0.015	0.029		L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4	L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065		L3	0.25 BSC		0.010 BSC		
D	8.51	9.65	0.335	0.380	2	L4	4.78	5.28	0.188	0.208	

Notes

- Dimensioning and tolerancing per ASME Y14.5 M-1994
- Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- Thermal pad contour optional within dimension E, L1, D1 and E1
- Dimension b1 and c1 apply to base metal only
- Datum A and B to be determined at datum plane H
- Controlling dimension: inch
- Outline conforms to JEDEC[®] outline TO-263AB



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